

preliminary

XPT IGBT

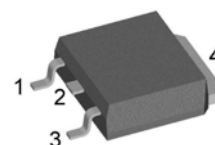
$$V_{CES} = 1200V$$

$$I_{C25} = 9A$$

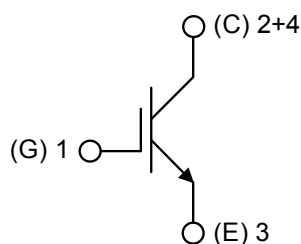
$$V_{CE(sat)} = 1.8V$$

Single IGBT

Part number

IXA4I1200UC
Marking on Product: X4TAU


Backside: collector



Features / Advantages:

- Easy paralleling due to the positive temperature coefficient of the on-state voltage
- Rugged XPT design (Xtreme light Punch Through) results in:
 - short circuit rated for 10 μ sec.
 - very low gate charge
 - low EMI
 - square RBSOA @ 3x I_C
- Thin wafer technology combined with the XPT design results in a competitive low $V_{CE(sat)}$

Applications:

- AC motor drives
- Solar inverter
- Medical equipment
- Uninterruptible power supply
- Air-conditioning systems
- Welding equipment
- Switched-mode and resonant-mode power supplies
- Inductive heating, cookers
- Pumps, Fans

Package: TO-252 (DPak)

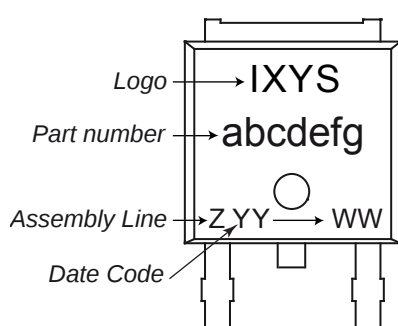
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

IGBT				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V _{CES}	collector emitter voltage	T _{VJ} = 25°C			1200	V	
V _{GES}	max. DC gate voltage				±20	V	
V _{GEM}	max. transient gate emitter voltage				±30	V	
I _{C25}	collector current	T _C = 25°C			9	A	
I _{C100}		T _C = 100°C			5	A	
P _{tot}	total power dissipation	T _C = 25°C			45	W	
V _{CE(sat)}	collector emitter saturation voltage	I _C = 3A; V _{GE} = 15 V		1.8	2.1	V	
				2.1		V	
V _{GE(th)}	gate emitter threshold voltage	I _C = 0.1mA; V _{GE} = V _{CE}	5.4	5.9	6.5	V	
I _{CES}	collector emitter leakage current	V _{CE} = V _{CES} ; V _{GE} = 0 V		0.1	0.1	mA	
						mA	
I _{GES}	gate emitter leakage current	V _{GE} = ±20 V			500	nA	
Q _{G(on)}	total gate charge	V _{CE} = 600 V; V _{GE} = 15 V; I _C = 3 A		12		nC	
t _{d(on)}	turn-on delay time	inductive load V _{CE} = 600V; I _C = 3A V _{GE} = ±15 V; R _G =330 Ω	T _{VJ} = 125°C	70		ns	
t _r	current rise time			40		ns	
t _{d(off)}	turn-off delay time			250		ns	
t _f	current fall time			100		ns	
E _{on}	turn-on energy per pulse			0.4		mJ	
E _{off}	turn-off energy per pulse			0.3		mJ	
RBSOA	reverse bias safe operating area	V _{GE} = ±15 V; R _G =330 Ω	T _{VJ} = 125°C				
I _{CM}		V _{CEmax} = 1200V			9	A	
SCSOA	short circuit safe operating area	V _{CEmax} = 900 V	T _{VJ} = 125°C				
t _{sc}	short circuit duration	V _{CE} = 900 V; V _{GE} = ±15 V			10	μs	
I _{sc}	short circuit current	R _G = 330 Ω; non-repetitive		12		A	
R _{thJC}	thermal resistance junction to case				2.7	K/W	
R _{thCH}	thermal resistance case to heatsink			0.50		K/W	

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Package TO-252 (DPak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			20	A
T_{VJ}	virtual junction temperature		-40		150	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		150	°C
Weight				0.3		g
F_c	mounting force with clip		20		60	N

Product Marking



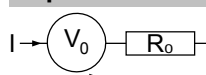
Part number

I = IGBT
 X = XPT IGBT
 A = Gen 1 / std
 4 = Current Rating [A]
 I = Single IGBT
 1200 = Reverse Voltage [V]
 UC = TO-252AA (DPak)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	IXA4I1200UC	X4TAU			

Equivalent Circuits for Simulation

* on die level

 $T_{VJ} = 150\text{ °C}$


IGBT

 $V_{0\max}$ threshold voltage

1.1

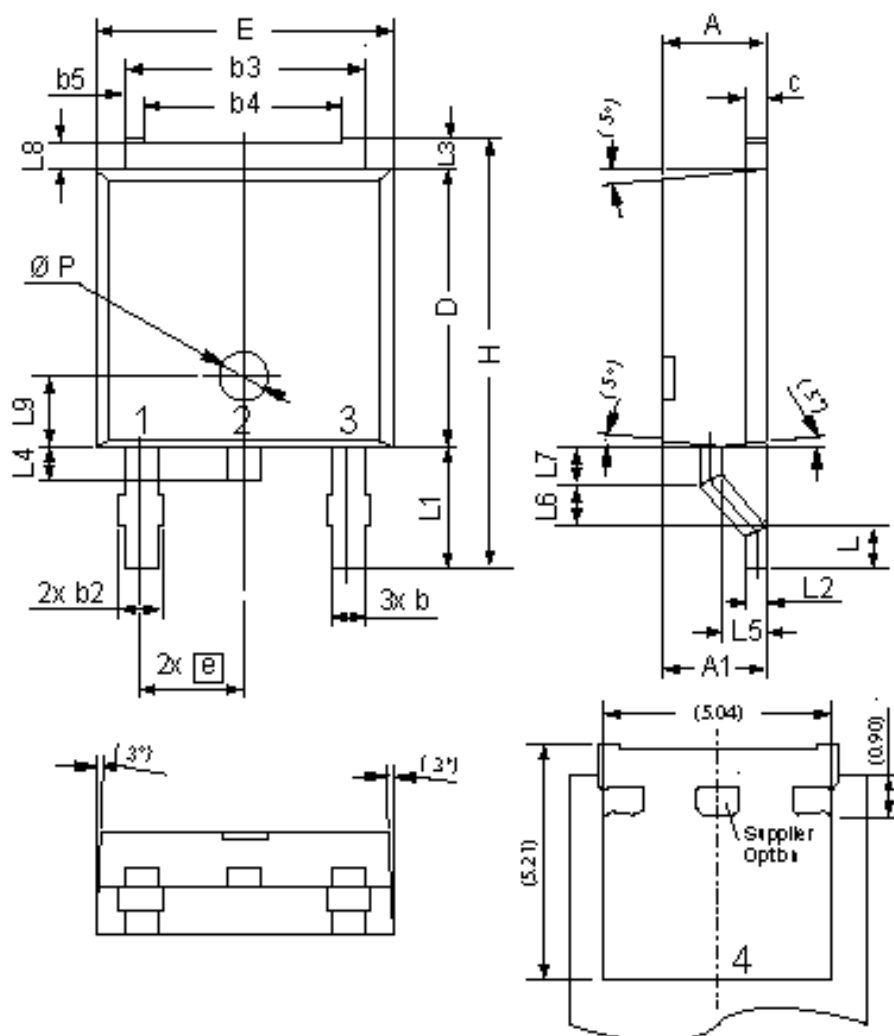
V

 $R_{0\max}$ slope resistance *

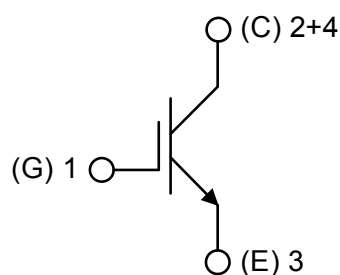
460

mΩ

Outlines TO-252 (DPak)



Dim	Millimeters		Inches	
	min	max	min	max
A	2.20	2.40	0.087	0.094
A1	2.10	2.50	0.083	0.098
b	0.66	0.86	0.026	0.034
b2	-	0.96	-	0.038
b3	5.04	5.64	0.198	0.222
b4	4.34 BSC		0.171 BSC	
b5	0.50 BSC		0.020 BSC	
c	0.40	0.86	0.016	0.034
D	5.90	6.30	0.232	0.248
E	6.40	6.80	0.252	0.268
e	2.10	2.50	0.083	0.098
H	9.20	10.10	0.362	0.398
L	0.55	1.28	0.022	0.050
L1	2.50	2.90	0.098	0.114
L2	0.40	0.60	0.016	0.024
L3	0.50	0.90	0.020	0.035
L4	0.60	1.00	0.024	0.039
L5	0.82	1.22	0.032	0.048
L6	0.79	0.99	0.031	0.039
L7	0.81	1.01	0.032	0.040
L8	0.40	0.80	0.016	0.031
L9	1.50 BSC		0.059 BSC	
Ø P	1.00 BSC		0.039 BSC	



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